

L Numb r	Hits	S arch T xt	DB	Time stamp
9	237	438/602,606.ccls.	USPAT	2003/07/03
40				12:53
10	570	257/200,201.ccls.	USPAT	2003/07/03
	1			12:53
11 12 13	194	257/615.ccls.	USPAT	2003/07/03
	470	400/000		12:53
	173	438/933.ccls.	USPAT	2003/07/03
	73	waterah taka 110 1		12:54
	/3	and the same of th	USPAT	2003/07/03
		michitsuta-tsutomu\$.in. hasegawa-taro\$.in.		12:57
14	20	fujii-takuya\$.in		
1-4	20	watanabe-takayuki\$.in.	US-PGPUB	2003/07/03
		michitsuta-tsutomu\$.in. hasegawa-taro\$.in. fujii-takuya\$.in		12:56
15	393	watanabe-takayuki\$.in.		
	333		EPO; JPO;	2003/07/03
		michitsuta-tsutomu\$.in. hasegawa-taro\$.in. fujii-takuya\$.in	DERWENT;	12:56
16	3408	("hcl" "HCl" hydrochl\$9) and (acetic	IBM_TDB	
		"ch.sub.3cooh" "CH.sub.3COOH") and	USPAT	2003/07/03
		etch\$3 and (indium "in" "In" "inp" "InP" "III"		13:02
		"V" gallium "ga" "Ga")		
17	93	("hcl" "HCl" hydrochl\$9) and (acetic	EDO: IDO:	2000/07/00
		"ch.sub.3cooh" "CH.sub.3COOH") and	EPO; JPO; DERWENT;	2003/07/03
		etch\$3 and (indium "in" "In" "inp" "Inp" "III"	IBM_TDB	13:02
		"V" gallium "ga" "Ga")	IBM_IDB	
18	885	("hcl" "HCl" hydrochl\$9) and (acetic	US-PGPUB	2003/07/03
		"ch.sub.3cooh" "CH.sub.3COOH") and	03-FGF0B	13:02
		etch\$3 and (indium "in" "In" "inp" "InP" "III"		13.02
		"V" gallium "ga" "Ga")		
19	802	(("hcl" "HCl" hydrochl\$9) and (acetic	USPAT	2003/07/03
		"ch.sub.3cooh" "CH.sub.3COOH") and		13:03
		etch\$3 and (indium "in" "In" "inp" "InP" "III"		10.00
		"V" gallium "ga" "Ga")) and (("hcl" "HCl"		
		hydrochl\$9) and (acetic "ch.sub.3cooh"		
ļ		"CH.sub.3COOH") same etch\$3)		
-	687	438/745,748.ccls.	USPAT	2003/07/03
				12:52
-	231	438/749,750.ccls.	USPAT	2003/07/03
				12:34
•	108	438/751.ccls.	USPAT	2003/07/03
				12:34
•	277	438/754.ccls.	USPAT	2003/07/03
		400-00		12:35
•	275	438/704.ccls.	USPAT	2003/07/03
	455	400.00		12:36
·	123	438/604.ccls.	USPAT	2003/07/03
	40-	430/005		12:36
	127	438/605.ccls.	USPAT	2003/07/03
				12:36